OKI Semiconductor

This version: Jan. 1998
Previous version: Aug. 1996

MSM52258

32,768-Word × 8-Bit CMOS STATIC RAM

DESCRIPTION

The MSM52258 is a 32,768-word by 8-bit CMOS fast static RAM featuring a single 5 V power supply operation and direct TTL input/output compatibility. Since the circuitry is completely static, external clock and refreshing operations are unnecessary, making this device very easy to use. The MSM52258 uses NMOS cells and CMOS peripherals and provides high-speed operation at 15 ns access time. Since the MSM52258 is provided with the $\overline{CS}$ and $\overline{OE}$ signals, it can connect with outputs of other chips in a wired OR technique, which provides easy memory expansion and bus line control.

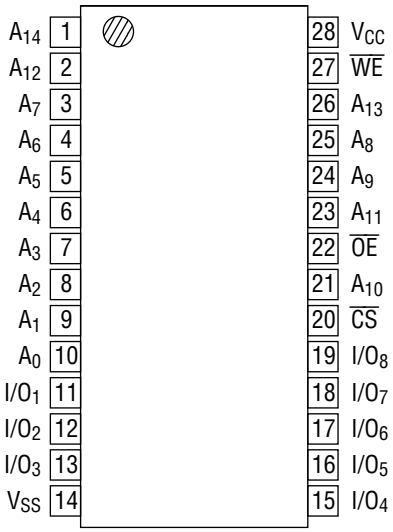
FEATURES

- 32,768-word × 8-bit configuration
- Single 5 V power supply
- Fully static operation
- Operating temperature range: Ta = 0°C to 70°C
- Low power dissipation
  Standby: 1 mA (Max.)
  Operation:
  - 15 170 mA (Max.)
  - 17 165 mA (Max.)
  - 20 160 mA (Max.)
- Access time:
  - 15 15 ns (Max.)
  - 17 17 ns (Max.)
  - 20 20 ns (Max.)
- (Input/Output) TTL compatible
- 3-state output
- Data retention available at power supply voltage 2 V
- Package:
  28-pin 300 mil plastic SOJ (SOJ28-P-300-1.27) (Product : MSM52258-xxJS)
  xx indicates speed rank.

PRODUCT FAMILY

Family	Access Time (Max.)	Package
MSM52258-15	15 ns	300 mil 28-pin SOJ
MSM52258-17	17 ns	
MSM52258-20	20 ns	

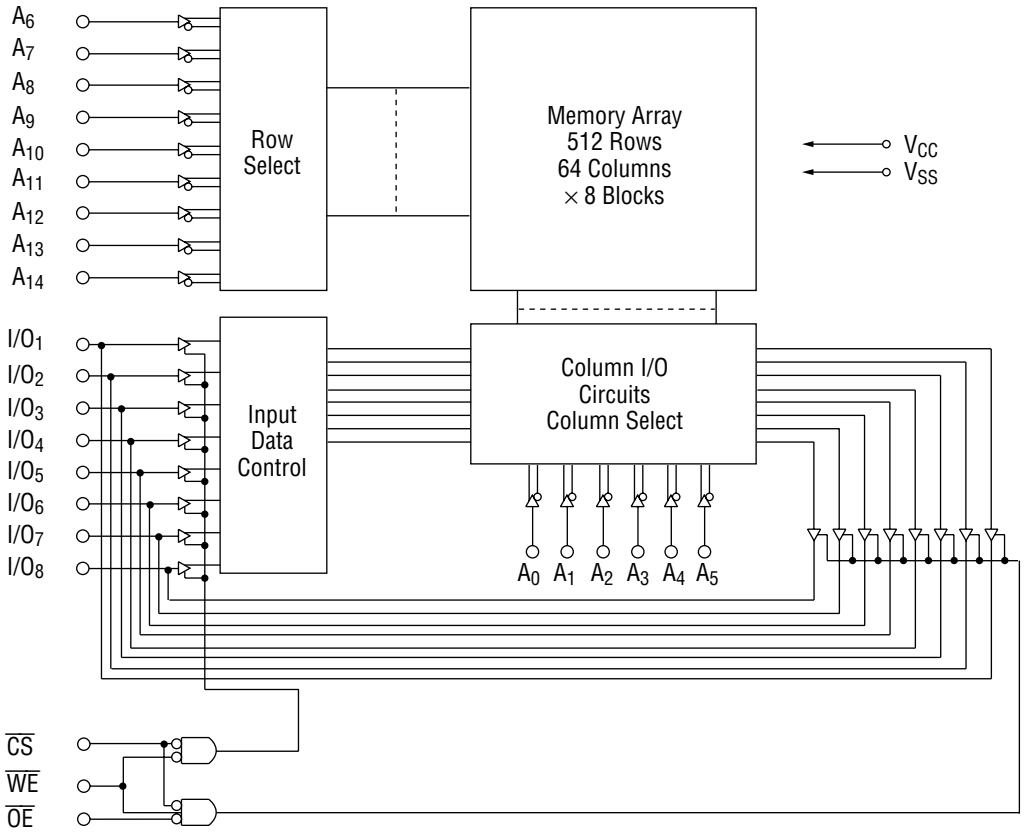
PIN CONFIGURATION (TOP VIEW)



28-Pin Plastic SOJ

Pin Name	Function
A_0 - A_{14}	Address Input
I/O_1 - I/O_8	Data Input/Output
$\overline{CS}$	Chip Select
$\overline{WE}$	Write Enable
$\overline{OE}$	Output Enable
V_{CC}, V_{SS}	Power Supply

BLOCK DIAGRAM



FUNCTION TABLE

Operating Mode	$\overline{CS}$	$\overline{WE}$	$\overline{OE}$	Operating Contents
Standby	H	*	*	Output Floating
Read Cycle	L	H	H	Output Floating
	L	H	L	Data Read
Write Cycle	L	L	*	Data Write

*Don't Care ("H" or "L")

ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Power Supply Voltage	V_{CC}	Ta = 25°C, for V_{SS}	–0.3 to 7.0	V
Pin Voltage	V_T		–0.3* to V_{CC} + 0.3	V
Power Dissipation	P_D	Ta = 25°C	1.0	W
Operating Temperature	T_{opr}	—	0 to 70	°C
Storage Temperature	T_{stg}	—	–55 to 125	°C

* –3.0 V Min. for pulse width less than 10 ns.

Recommended Operating Conditions

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Power Supply Voltage	V_{CC}	—	4.5	5	5.5	V
	V_{SS}		0	0	0	V
Input High Voltage	V_{IH}	V_{CC} = 5 V ±10%	2.2	—	V_{CC} + 0.3	V
Input Low Voltage	V_{IL}		–0.3*	—	0.8	V
Load Capacitance	C_L	—	—	—	30	pF

* –3.0 V Min. for pulse width less than 10 ns.

Capacitance

(Ta = 25°C, f = 1 MHz)

Parameter	Symbol	Condition	Min.	Max.	Unit
Input Capacitance	C_I	V_I = 0 V	—	6	pF
Input/Output Capacitance	$C_{I/O}$	$V_{I/O}$ = 0 V	—	8	pF

Note: This parameter is periodically sampled and not 100% tested.

DC Characteristics

(V_{CC} = 5 V ±10%, Ta = 0°C to 70°C)

Parameter	Symbol	Condition	MSM52258			Unit
			Min.	Typ.	Max.	
Input Leakage Current	I_{LI}	V_I = 0 to V_{CC}	–10	—	10	µA
Input/Output Leakage Current	I_{LO}	$\overline{CS}$ = V_{IH} or $\overline{OE}$ = V_{IH}, $V_{I/O}$ = 0 to V_{CC}	–10	—	10	µA
Output High Voltage	V_{OH}	I_{OH} = –4 mA	2.4	—	—	V
Output Low Voltage	V_{OL}	I_{OL} = 8 mA	—	—	0.4	V
Standby Power Supply Current	I_{CCS}	$\overline{CS}$ ≥ V_{CC} – 0.2 V, V_I ≤ 0.2 V or V_I ≥ V_{CC} – 0.2 V	—	—	1	mA
	I_{CCS1}	$\overline{CS}$ = V_{IH}, Min. cycle	—	—	20	mA
Operating Power Supply Current	I_{CCA}	Min. cycle, I_{OUT} = 0 mA	—	—	①	mA

① 52258-15 170 mA
52258-17 165 mA
52258-20 160 mA

AC Characteristics

Test Conditions

Parameter	Condition
Input Pulse Level	V_{IH} = 3.0 V, V_{IL} = 0.0 V
Input Rise and Fall Times	3 ns
Input/Output Timing Level	1.5 V
Output Load	See Figures

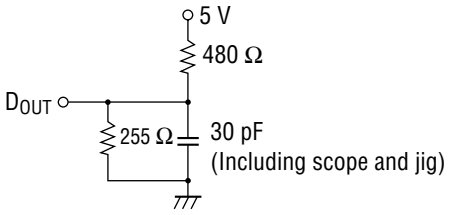


Figure 1 Output Load

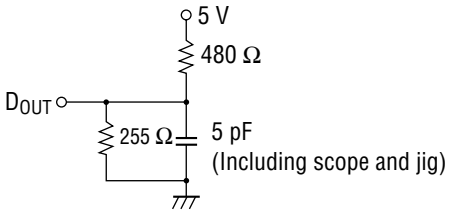


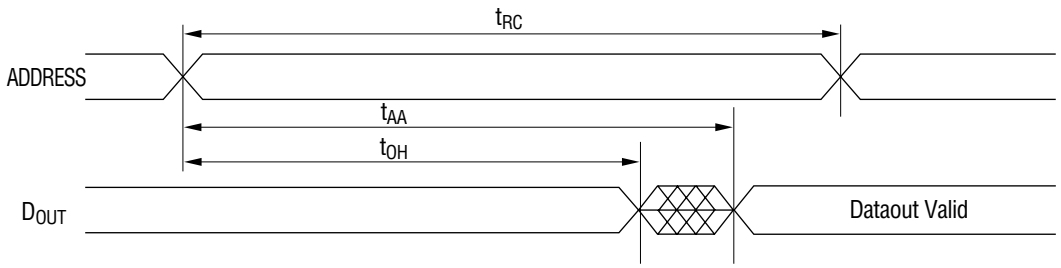
Figure 2 Output Load
(t_{OLZ}, t_{CLZ}, t_{OHZ}, t_{CHZ}, t_{WLZ}, t_{WHZ})

Read Cycle

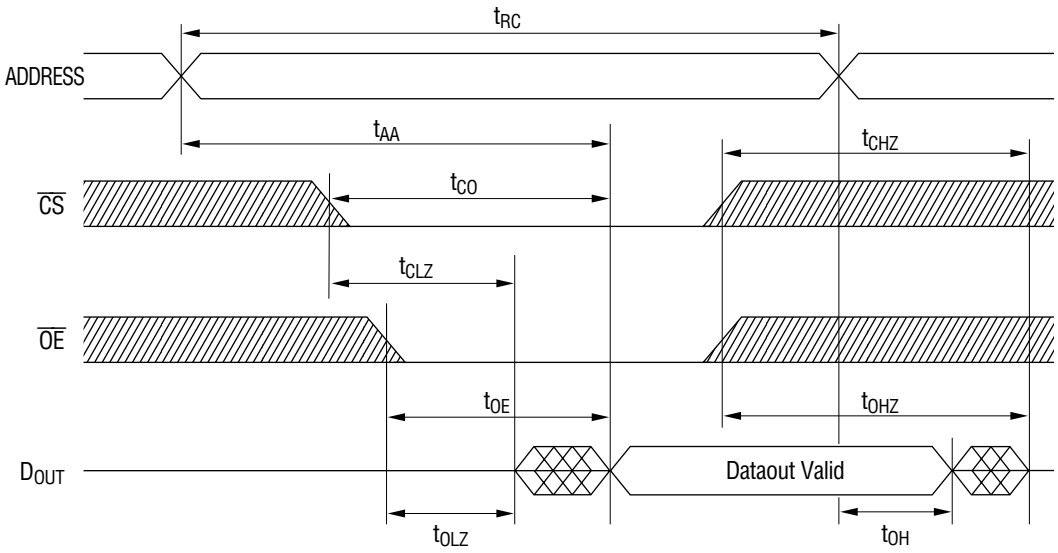
(V_{CC} = 5 V ±10%, Ta = 0°C to 70°C)

Parameter	Symbol	MSM52258-15		MSM52258-17		MSM52258-20		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle Time	t_{RC}	15	—	17	—	20	—	ns
Address Access Time	t_{AA}	—	15	—	17	—	20	ns
$\overline{CS}$ Access Time	t_{CO}	—	15	—	17	—	20	ns
$\overline{OE}$ Access Time	t_{OE}	—	8	—	9	—	10	ns
$\overline{CS}$ to Output in Low-Z	t_{CLZ}	3	—	3	—	3	—	ns
$\overline{OE}$ to Output in Low-Z	t_{OLZ}	0	—	0	—	0	—	ns
Output Hold Time from Address Change	t_{OH}	3	—	3	—	3	—	ns
$\overline{CS}$ to Output in High-Z	t_{CHZ}	—	7	—	7	—	8	ns
$\overline{OE}$ to Output in High-Z	t_{OHZ}	—	7	—	7	—	8	ns

Address Controlled Read ($\overline{WE}$ = H, $\overline{CS}$ = L, $\overline{OE}$ = L)



$\overline{CS}$, $\overline{OE}$ Controlled Read ($\overline{WE}$ = H)



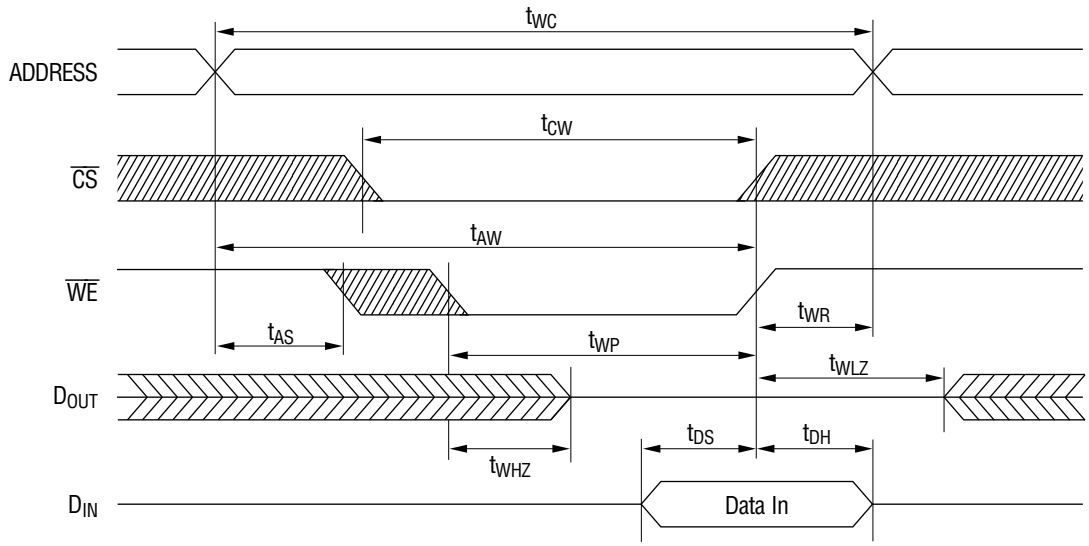
Notes : 1. A read cycle occurs during the overlap of $\overline{CS}$ = "L", $\overline{OE}$ = "L" and $\overline{WE}$ = "H".
2. t_{CHZ} and t_{OHZ} are specified by the time when DATA is floating, not defined by the output level.

Write Cycle

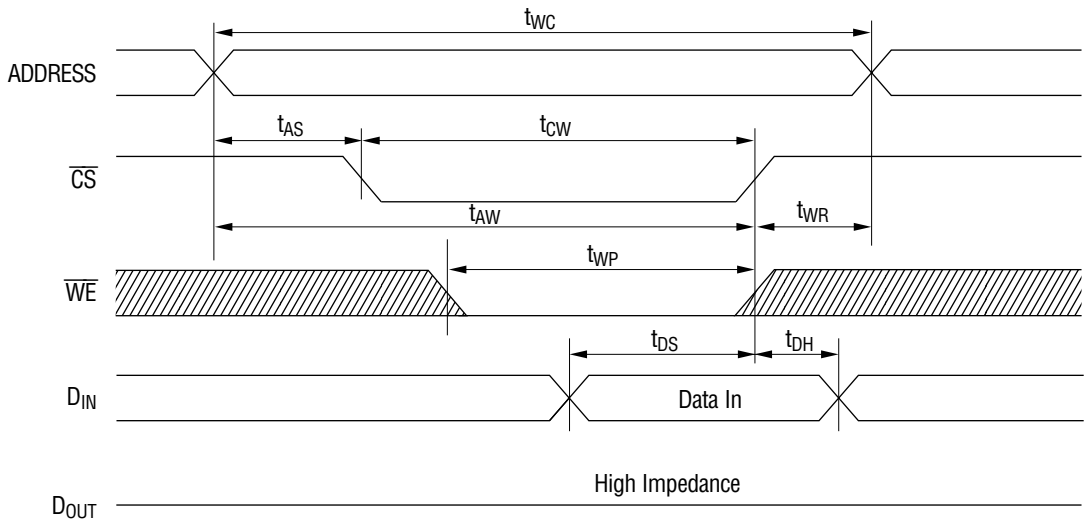
(V_{CC} = 5 V ±10%, Ta = 0°C to 70°C)

Parameter	Symbol	MSM52258-15		MSM52258-17		MSM52258-20		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Write Cycle Time	t_{WC}	15	—	17	—	20	—	ns
Address Setup Time	t_{AS}	0	—	0	—	0	—	ns
Write Pulse Width	t_{WP}	12	—	13	—	15	—	ns
Write Recovery Time	t_{WR}	0	—	0	—	0	—	ns
Data Setup Time	t_{DS}	7	—	8	—	10	—	ns
Data Hold Time	t_{DH}	0	—	0	—	0	—	ns
$\overline{WE}$ to Output in High-Z	t_{WHZ}	—	7	—	7	—	8	ns
$\overline{CS}$ to End of Write	t_{CW}	12	—	13	—	15	—	ns
Address Valid to End of Write	t_{AW}	12	—	13	—	15	—	ns
Output Active from End of Write	t_{WLZ}	0	—	0	—	0	—	ns

$\overline{WE}$ Controlled Write ($\overline{OE}$ = L)



$\overline{CS}$ Controlled Write ($\overline{OE}$ = H)

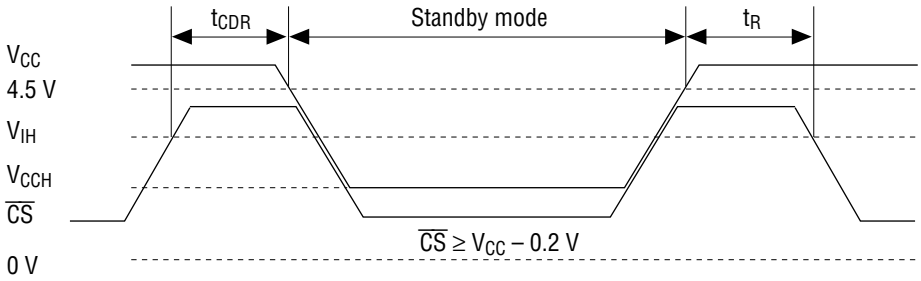


Notes:
1. A write cycle occurs during the overlap of $\overline{CS}$ = "L" and $\overline{WE}$ = "L".
2. $\overline{OE}$ may be either of "H" or "L" in the write cycle.
3. t_{AS} is specified from $\overline{CS}$ = "L" or $\overline{WE}$ = "L", whichever occurs last.
4. t_{WP} is an overlap time of $\overline{CS}$ = "L" and $\overline{WE}$ = "L".
5. t_{WR}, t_{DS} and t_{DH} are specified from $\overline{CS}$ = "H" or $\overline{WE}$ = "H", whichever occurs first.
6. t_{WHZ} is specified by the time when DATA output is floating, not defined by the output level.
7. When I/O pins are in the output mode, don't apply the inverted input signal to the output pins.

Data Retention Characteristics

(Ta = 0°C to 70°C)

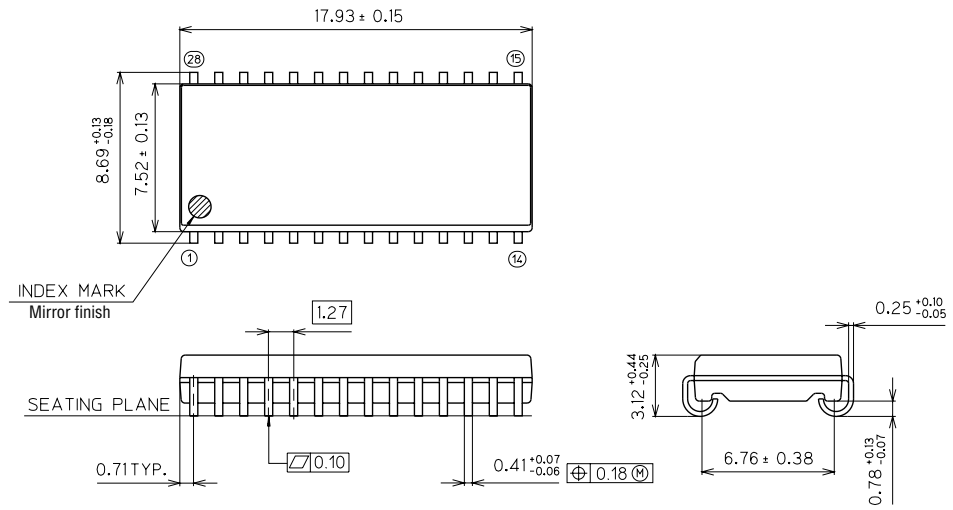
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Data Retention Power Supply Voltage	V_{CCH}	$\overline{CS} \geq V_{CC} - 0.2$ V	2.0	—	—	V
Data Retention Power Supply Current	I_{CCH}	V_{CC} = 3 V, $\overline{CS} \geq V_{CC} - 0.2$ V	—	—	500	µA
Chip Deselect to Data Retention Time	t_{CDR}	—	0	—	—	ns
Operation Recovery Time	t_R	—	5	—	—	ms



PACKAGE DIMENSIONS

(Unit : mm)

SOJ28-P-300-1.27



Package material	Epoxy resin
Lead frame material	Cu alloy
Pin treatment	Solder plating
Solder plate thickness	5 μm or more
Package weight (g)	0.80 TYP.

Notes for Mounting the Surface Mount Type Package

The SOP, QFP, TSOP, SOJ, QFJ (PLCC), SHP and BGA are surface mount type packages, which are very susceptible to heat in reflow mounting and humidity absorbed in storage.
Therefore, before you perform reflow mounting, contact Oki's responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).